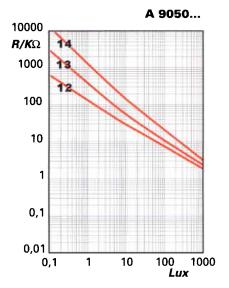
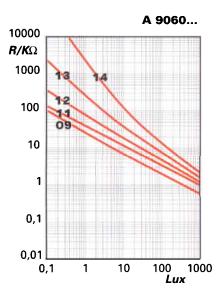
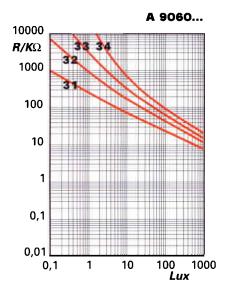
A 9060... A 9050...

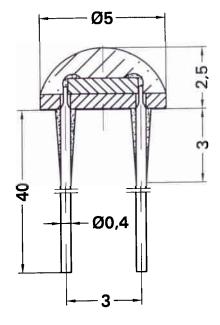


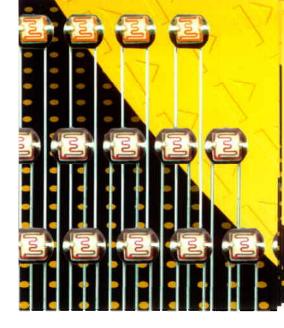


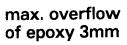
R 10	Resistance at $E = 10$ lux light intensity	Tst	Storage Temperature
R 100	Resistance at $E = 100$ lux light intensity	TC	Thermal Coefficient
Ro1	Dark Resistance after 1 sec (E = 0)	ton	Rise Time to 63% of final I (R10)
Ros	Dark Resistance after 5 sec (E = 0)	toff	Decay Time to 37% of initial I (R ₁₀)
Y10/100	Sensitivity log (R10/R100) / log (100lux/10 lux)	V_{max}	Maximum Operating Voltage at $E = 0$ lux
λpeak	Peak Spectral Sensitivity	Pmax	Power Dissipation at 25°C Ambient Temp.
Тор	Operating Temperature		

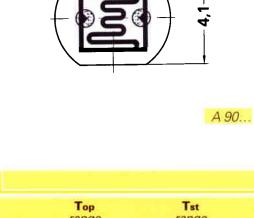
уре	R 10	R 100	Ro1	Ros	Y10/100	A peak
	[kΩ]	typ. [kΩ]	min. [Μ Ω]	min. [Μ Ω]	typ.	[nm]
ll readings taken at standa	ard light A (2854 K color	temperature) after 2 h	ours of preillumination	at 500 lux		
A 9060 09	4 11	2	0.04	0.12	0.65	600
A 9060 11	9 20	3.5	0.06	0.18	0.65	600
A 9060 12	16 33	5	0.18	0.5	0.7	600
A 9060 13	27 94	8	0.5	1.5	0.8	600
A 9060 14	77 340	15	1.5	5.0	0.9	600
A 9060 31	60 130	23	0.4	1.2	0.65	600
A 9060 32	120 210	35	1.0	3.0	0.7	600
A 9060 33	200 580	50	3.0	9.0	0.8	600
A 9060 34	500 1200	100	5.0	15.0	0.9	600
A 9050 12	18 44	7	0.15	0.45	0.65	530
A 9050 13	36 88	12	0.4	1.2	0.7	530
A 9050 14	70 200	20	1.0	3.0	0.75	530
A 9072 series	low light resist	tance /fast respon	se characteristics/	on request	and the control of th	e o Pair se ser est editables à la serie describé d'











Тор	Tst	TC	ton	toff	Vmax	Pmax
range [°C]	range [°C]	10 lux [% /°K]	typ. [msec]	typ. [msec]	[V]	[mW]
-20 +70	-20 +80	0.4	50	40	100	90
-20 +70	-20 +80	0.3	60	40	150	90
-20 +70	-20 +80	0.35	50	35	150	90
-20 +70	-20 +80	0.4	35	30	150	90
-20 +70	-20 +80	0.5	25	20	150	90
-20 +70	-20 +80	0.3	60	40	300	90
-20 +70	-20 +80	0.35	50	35	300	90
-20 +70	-20 +80	0.4	35	30	300	90
-20 +70	-20 +80	0.5	25	20	300	90
-20 +70	-20 +80	0.2	60	40	150	90
-20 +70	-20 +80	0.3	50	30	150	90
-20 +70	-20 +80	0.3	40	30	150	90